Quad SPDT Switch

Data Sheet

ADG333A

FEATURES

- 44 V supply maximum ratings
- V_{SS} to V_{DD} analog signal range
- Low on resistance (45 Ω max)
- Low ΔR_{ON} (5 Ω max)
- Low R_{ON} match (4 Ω max)
- Low power dissipation
- Fast switching times
  - t_{ON} < 175 ns
  - t_{OFF} < 145 ns
- Low leakage currents (5 nA max)
- Low charge injection (10 pC max)
- Break-before-make switching action

APPLICATIONS

- Audio and video switching
- Battery-powered systems
- Test equipment
- Communication systems

FUNCTIONAL BLOCK DIAGRAM

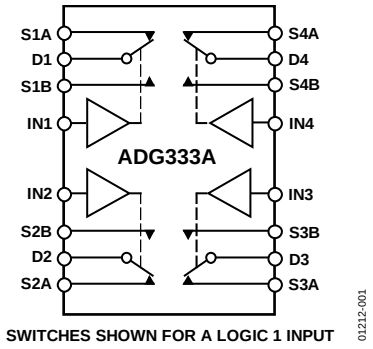

Figure 1.

GENERAL DESCRIPTION

The ADG333A is a monolithic complementary metal-oxide semiconductor (CMOS) device comprising four independently selectable single-pole, double-throw (SPDT) switches. It is designed on a linear compatible CMOS (LC²MOS) process, which provides low power dissipation yet achieves a high switching speed and a low on resistance.

The on-resistance profile is very flat over the full analog input range, ensuring good linearity and low distortion when switching audio signals. High switching speed also makes the device suitable for video signal switching. CMOS construction ensures ultralow power dissipation, making the device ideally suited for portable, battery-powered instruments.

When they are on, each switch conducts equally well in both directions and has an input signal range that extends to the power supplies. In the off condition, signal levels up to the supplies are blocked. All switches exhibit break-before-make switching action for use in multiplexer applications. Low charge inject is inherent in the design.

PRODUCT HIGHLIGHTS

1. Extended signal range. The ADG333A is fabricated on an enhanced LC²MOS process, giving an increased signal range which extends to the supply rails.
2. Low power dissipation.
3. Low R_{ON}.
4. Single-supply operation. For applications in which the analog signal is unipolar, the ADG333A can be operated from a single rail power supply. The device is fully specified with a single 12 V supply.

Rev. B

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TABLE OF CONTENTS

REVISION HISTORY

6/2016—Rev. A to Rev. B

Changes to V_{DD} Parameter, Table 2 4
Updated Outline Dimensions 12
Changes to Ordering Guide 13

3/2005—Rev. 0 to Rev. A

Updated Format ..... Universal
Changes to Specifications Section 3
Updated Outline Dimensions 12
Changes to Ordering Guide 12

10/1995—Revision 0: Initial Version

SPECIFICATIONS

DUAL SUPPLY

V_{DD} = +15 V, V_{SS} = −15 V, GND = 0 V, unless otherwise noted.[1]

Table 1.

Parameter	+25°C	−40°C to +85°C	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		V_{SS} to V_{DD}	V	
R_{ON}	20		Ω typ	V_D = ±10 V, I_S = −1 mA
	45	45	Ω max	
ΔR_{ON}		5	Ω max	V_D = ±5 V, I_S = −10 mA
R_{ON} Match		4	Ω max	V_D = ±10 V, I_S = −10 mA
LEAKAGE CURRENTS				V_{DD} = +16.5 V, V_{SS} = −16.5 V
Source Off Leakage I_S (OFF)	±0.1		nA typ	V_D = ±15.5 V, V_S = +15.5 V
	±0.25	±3	nA max	Figure 15
Channel On Leakage I_D, I_S (ON)	±0.1		nA typ	V_S = V_D = ±15.5 V
	±0.4	±5	nA max	Figure 16
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.4	V min	
Input Low Voltage, V_{INL}		0.8	V max	
Input Current				
I_{INL} or I_{INH}		±0.005	μA typ	V_{IN} = 0 V or V_{DD}
		±0.5	μA max	
DYNAMIC CHARACTERISTICS[2]				
t_{ON}	90		ns typ	R_L= 300 Ω, C_L = 35 pF; V_S = ±10 V; Figure 17
		175	ns max	
t_{OFF}	80		ns typ	R_L = 300 Ω, C_L = 35 pF; V_S = ±10 V; Figure 17
		145	ns max	
Break-Before-Make Delay, t_{OPEN}	10		ns min	R_L = 300 Ω, C_L= 35 pF; V_S = +5 V; Figure 18
Charge Injection	2		pC typ	V_D = 0 V, R_D = 0 Ω, C_L= 10 nF; V_{DD} = +15 V, V_{SS} = −15 V; Figure 19
	10		pC max	
Off Isolation	72		dB typ	R_L = 75 Ω, C_L = 5 pF, f = 1 MHz; V_S = 2.3 V rms; Figure 20
Channel-to-Channel Crosstalk	85		dB typ	R_L = 75 Ω, C_L = 5 pF, f = 1 MHz; V_S = 2.3 V rms; Figure 21
C_S (OFF)	7		pF typ	
C_D, C_S (ON)	26		pF typ	
POWER REQUIREMENTS				
I_{DD}	0.05		mA typ	Digital inputs = 0 V or 5 V
	0.25	0.35	mA max	
I_{SS}	0.01		μA typ	
	1	5	μA max	
V_{DD}/V_{SS}		±3/±20	V min/V max	$\|V_{DD}\| = \|V_{SS}\|$

[1] Temperature range is as follows: B version: −40°C to +85°C.
[2] Guaranteed by design; not subject to production test.

SINGLE SUPPLY

V_{DD} = +12 V, V_{SS} = 0 V ± 10%, GND = 0 V, unless otherwise noted.[1]

Table 2.

Parameter	+25°C	−40°C to +85°C	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		0 V to V_{DD}	V	
R_{ON}	35		Ω typ	V_D = 1 V, 10 V, I_S = −1 mA
		75	Ω max	
LEAKAGE CURRENTS				V_{DD} = 13.2 V
Source Off Leakage I_S (OFF)	±0.1		nA typ	V_D = 12.2 V/1 V, V_S = 1 V/12.2 V
	±0.25	±3	nA max	Figure 15
Channel On Leakage I_D, I_S (ON)	±0.1		nA typ	V_S = V_D = 12.2 V/1 V
	±0.4	±5	nA max	Figure 16
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.4	V min	
Input Low Voltage, V_{INL}		0.8	V max	
Input Current				
I_{INL} or I_{INH}		±0.005	μA typ	V_{IN} = 0 V or V_{DD}
		±0.5	μA max	
DYNAMIC CHARACTERISTICS[2]				
t_{ON}	110		ns typ	R_L = 300 Ω, C_L = 35 pF; V_S = 8 V; Figure 17
		200	ns max	
t_{OFF}	100		ns typ	R_L = 300 Ω, C_L = 35 pF; V_S = 8 V; Figure 17
		180	ns max	
Break-Before-Make Delay, t_{OPEN}	10		ns min	R_L = 300 Ω, C_L = 35 pF; V_S = 5 V; Figure 18
Charge Injection	5		pC typ	V_D = 6 V, R_D = 0 W, C_L = 10 nF; V_{DD} = 12 V, V_{SS} = 0 V; Figure 19
Off Isolation	72		dB typ	R_L = 75 Ω, C_L = 5 pF, f = 1 MHz; V_S = 1.15 V rms; Figure 20
Channel-to-Channel Crosstalk	85		dB typ	R_L = 75 Ω, C_L = 5 pF, f = 1 MHz; V_S = 1.15 V rms; Figure 21
C_S (OFF)	12		pF typ	
C_D, C_S (ON)	25		pF typ	
POWER REQUIREMENTS				V_{DD} = 13.5 V
I_{DD}	0.05		mA typ	Digital inputs = 0 V or 5 V
	0.25	0.35	mA max	
V_{DD}		3/30	V min/V max	

[1] Temperature range is as follows: B Version: −40°C to +85°C.
[2] Guaranteed by design; not subject to production test.

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C unless otherwise noted.

Table 3.

Parameter	Min
V_{DD} to V_{SS}	+44 V
V_{DD} to GND	−0.3 V to +30 V
V_{SS} to GND	+0.3 V to −30 V
Analog, Digital Inputs[1]	V_{SS} − 2 V to V_{DD} + 2 V or 20 mA, whichever occurs first
Continuous Current, S or D	20 mA
Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle Max)	40 mA
Operating Temperature Range	
Industrial (B Version)	−40°C to +85°C
Storage Temperature Range	−65°C to +125°C
Junction Temperature	150°C
θ_{JA}, Thermal Impedance	
PDIP Package	103°C/W
SOIC Package	74°C/W
SSOP Package	130°C/W
Lead Temperature, Soldering	
10 sec	260°C
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C

[1] Overvoltage at IN, S, or D is clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Table 4. Truth Table

Logic	Switch A	Switch B
0	Off	On
1	On	Off

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TERMINOLOGY

R_{ON}
Ohmic resistance between D and S.

ΔR_{ON}
R_{ON} variation due to a change in the analog input voltage with a constant load current.

R_{ON} Match
Difference between the R_{ON} of any two channels.

I_S (OFF)
Source leakage current with the switch off.

I_D (OFF)
Drain leakage current with the switch off.

I_D, I_S (ON)
Channel leakage current with the switch on.

V_D (V_S)
Analog voltage on Terminal D and Terminal S.

C_S (OFF)
Off switch source capacitance.

C_D (OFF)
Off switch drain capacitance.

C_D, C_S (ON)
On switch capacitance.

t_{ON}
Delay between applying the digital control input and the output switching on.

t_{OFF}
Delay between applying the digital control input and the output switching off.

t_{OPEN}
Break-before-make delay when switches are configured as a multiplexer.

V_{INL}
Maximum input voltage for Logic 0.

V_{INH}
Minimum input voltage for Logic 1.

I_{INL} (I_{INH})
Input current of the digital input.

Crosstalk
A measure of unwanted signal which is coupled through from one channel to another as a result of parasitic capacitance.

Off Isolation
A measure of unwanted signal coupling through an off switch.

Charge Injection
A measure of the glitch impulse transferred from the digital input to the analog output during switching.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

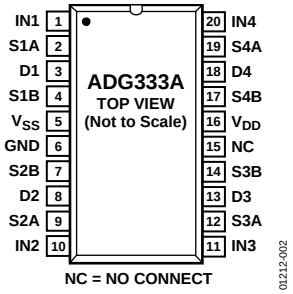


Figure 2. PDIP Pin Configuration

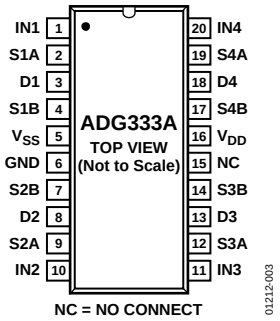


Figure 3. SOIC Pin Configuration

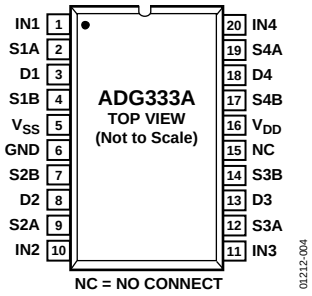


Figure 4. SSOP Pin Configuration

Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 10, 11, 20	IN1, IN2, IN3, IN4	Logic Control Input.
2, 4, 7, 9, 12, 14, 17, 19	S1A, S1B, S2B, S2A, S3A, S3B, S4B, S4A	Source Terminal. Can be an input or an output.
3, 8, 13, 18	D1, D2, D3, D4	Drain Terminal. Can be an input or an output.
5	V_{SS}	Most Negative Power Supply Potential in Dual Supplies. In single-supply applications, it can be connected to ground.
6	GND	Ground (0 V) Reference.
15	NC	No Connect.
16	V_{DD}	Most Positive Power Supply Potential.

TYPICAL PERFORMANCE CHARACTERISTICS

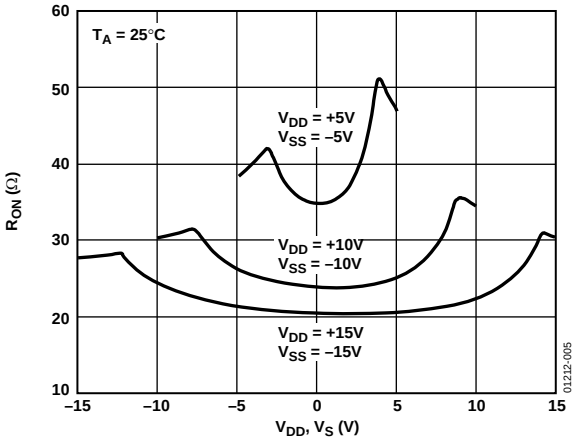


Figure 5. R_{ON} as a Function of V_D (V_S), Dual Supply

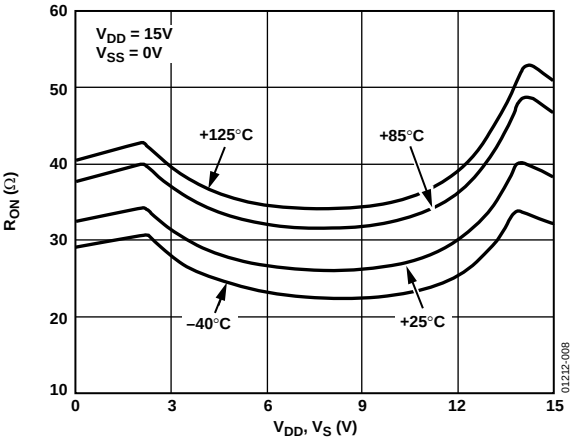


Figure 8. R_{ON} as a Function of V_D (V_S) for Different Temperatures, Single Supply

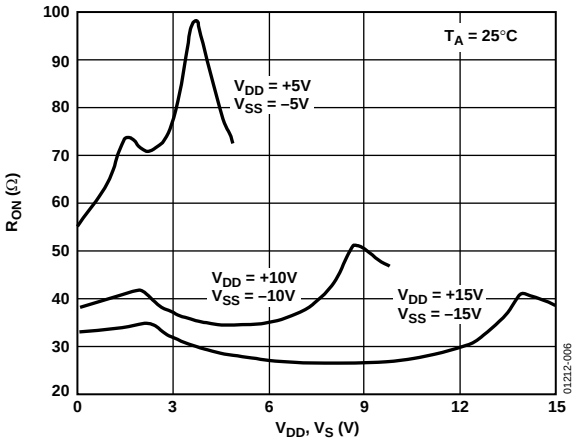


Figure 6. R_{ON} as a Function of V_D (V_S), Single Supply

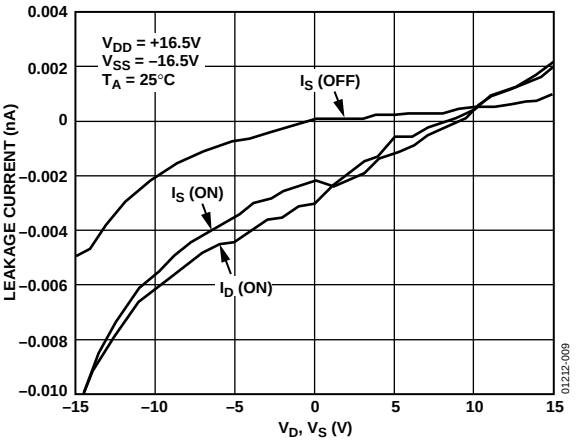


Figure 9. Leakage Currents as a Function of V_D (V_S), Dual Supply

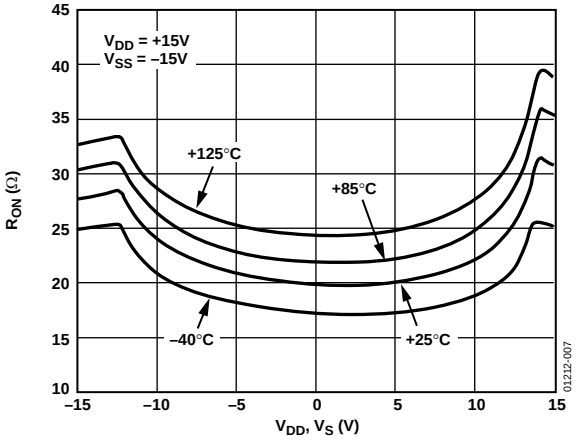


Figure 7. R_{ON} as a Function of V_D (V_S) for Different Temperatures, Dual Supply

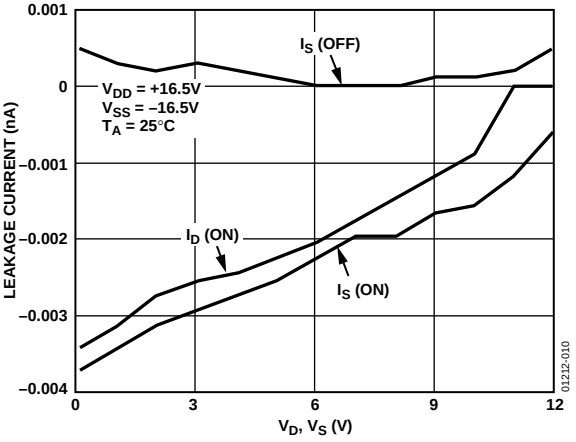


Figure 10. Leakage Currents as a Function of V_D (V_S), Single Supply

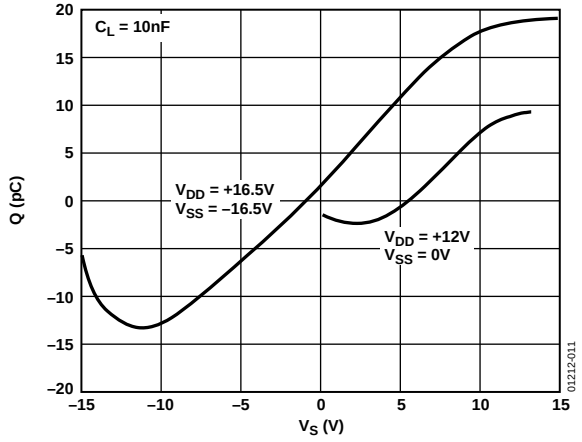


Figure 11. Charge Injection as a Function of V_S

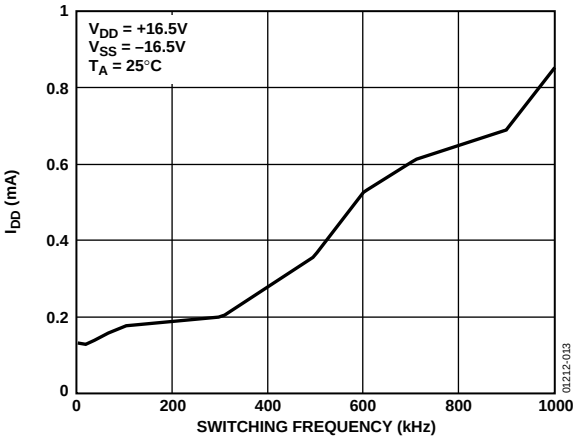


Figure 13. I_{DD} as a Function of Switching Frequency

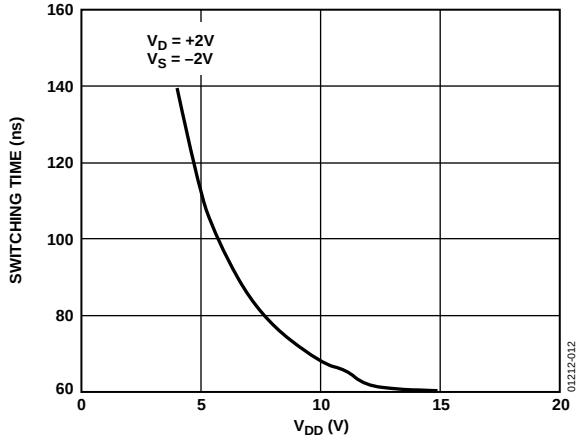


Figure 12. Switching Time as a Function of V_D

TEST CIRCUITS

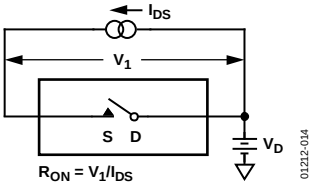


Figure 14. On Resistance

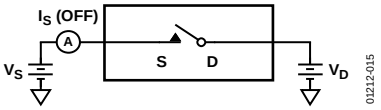


Figure 15. Off Leakage

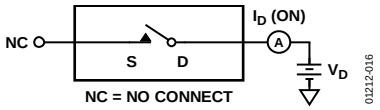
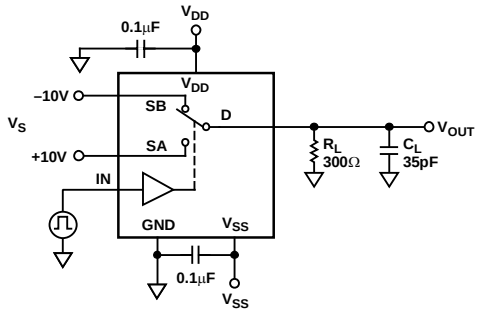


Figure 16. On Leakage



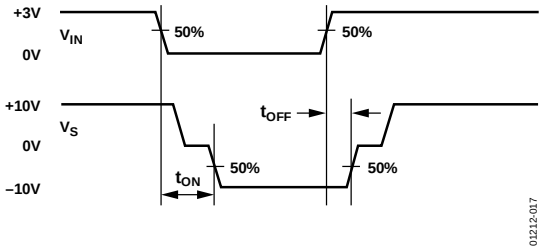
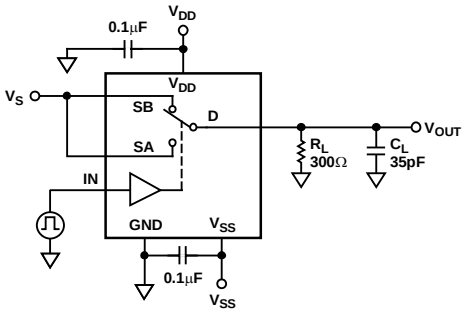


Figure 17. Switching Times



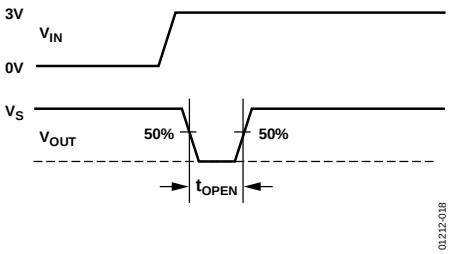
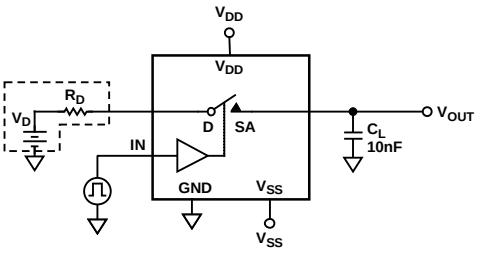


Figure 18. Break-Before-Make Delay, t_{OPEN}



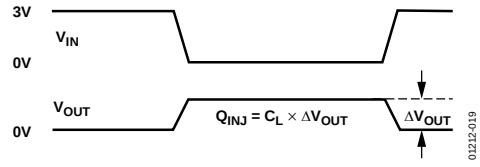


Figure 19. Charge Injection

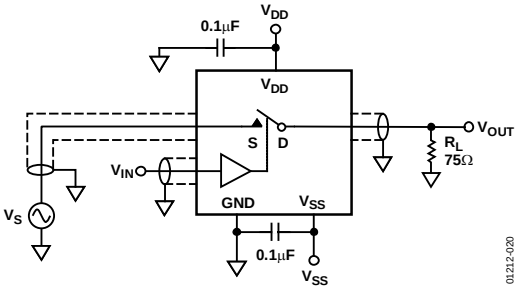


Figure 20. Off Isolation

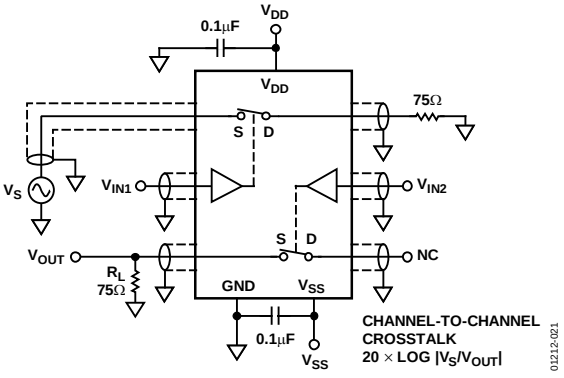


Figure 21. Channel-to-Channel Crosstalk

APPLICATIONS INFORMATION

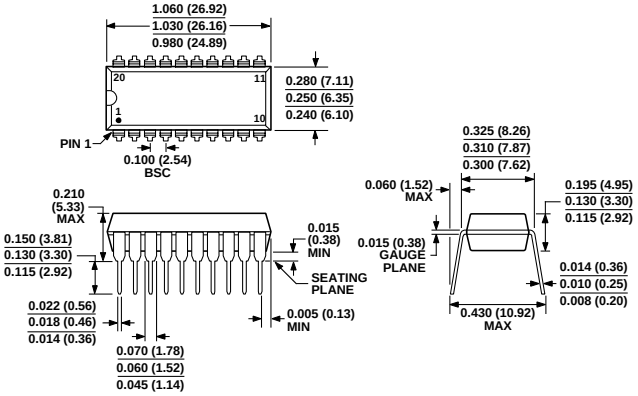
ADG333A SUPPLY VOLTAGES

The ADG333A can operate from a dual or signal supply. V_{SS} should be connected to GND when operating with a single supply. When using a dual supply, the ADG333A can also operate with unbalanced supplies; for example V_{DD} = 20 V and V_{SS} = −5 V. The only restrictions are that V_{DD} to GND must not exceed 30 V, V_{SS} to GND must not drop below −30 V, and V_{DD} to V_{SS} must not exceed +44 V. It is important to remember that the ADG333A supply voltage directly affects the input signal range, the switch on resistance and the switching times of the device. The effects of the power supplies on these characteristics can be clearly seen from the Typical Performance Characteristics curves.

POWER SUPPLY SEQUENCING

When using CMOS devices, care must be taken to ensure correct power-supply sequencing. Incorrect power-supply sequencing can result in the device being subjected to stresses beyond those listed in the Absolute Maximum Ratings. This is also true for the ADG333A. Always turn on V_{DD} first, followed by V_{SS} and the logic signals. An external signal within the maximum specified ratings can then be safely presented to the source or drain of the switch.

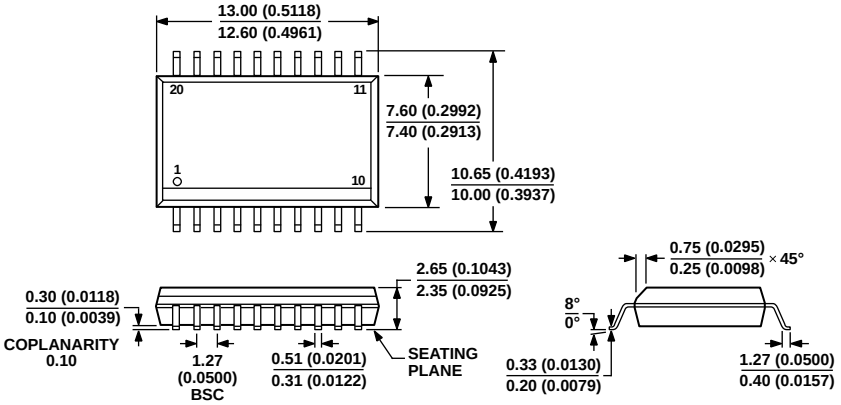
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-001-AD

CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 22. 20-Lead Plastic Dual In-Line Package [PDIP]
Narrow Body (N-20)
Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MS-013-AC

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

06-07-2006-A

Figure 23. 20-Lead Standard Small Outline Package [SOIC_W]
Wide Body (RW-20)
Dimensions shown in millimeters and (inches)

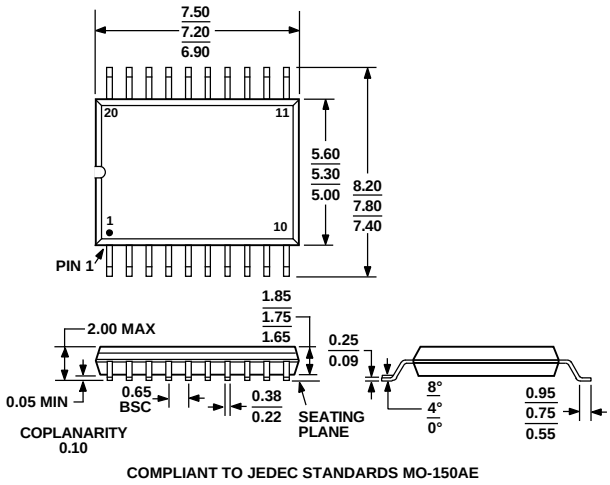


Figure 24. 20-Lead Shrink Small Outline Package [SSOP]
(RS-20)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Package Description	Package Option
ADG333ABNZ	−40°C to +85°C	20-Lead Plastic Dual In-Line Package [PDIP]	N-20
ADG333ABR	−40°C to +85°C	20-Lead Standard Small Outline Package [SOIC_W]	RW-20
ADG333ABR-REEL	−40°C to +85°C	20-Lead Standard Small Outline Package [SOIC_W]	RW-20
ADG333ABRZ	−40°C to +85°C	20-Lead Standard Small Outline Package [SOIC_W]	RW-20
ADG333ABRZ-REEL	−40°C to +85°C	20-Lead Standard Small Outline Package [SOIC_W]	RW-20
ADG333ABRS	−40°C to +85°C	20-Lead Shrink Small Outline Package [SSOP]	RS-20
ADG333ABRS-REEL	−40°C to +85°C	20-Lead Shrink Small Outline Package [SSOP]	RS-20
ADG333ABRSZ	−40°C to +85°C	20-Lead Shrink Small Outline Package [SSOP]	RS-20
ADG333ABRSZ-REEL	−40°C to +85°C	20-Lead Shrink Small Outline Package [SSOP]	RS-20

[1] Z = RoHS Compliant Part.

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